

# BC327AP Transistors

## Si PNP Lo-Pwr BJT

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Military/High-Rel N

V(BR)CEO (V) 45

V(BR)CBO (V)

I(C) Max. (A) 800m

Absolute Max. Power Diss. (W) 625m

Maximum Operating Temp (°C) 150°

I(CBO) Max. (A) 100n×

@V(CBO) (V) (Test Condition)

V(CE)sat Max. (V)

@I(C) (A) (Test Condition)

@I(B) (A) (Test Condition)

h(FE) Min. Current gain. 160

h(FE) Max. Current gain.

@I(C) (A) (Test Condition) 100m

@V(CE) (V) (Test Condition) 1.0

f(T) Min. (Hz) Transition Freq 100M

@I(C) (A) (Test Condition)

@V(CE) (V) (Test Condition)

C(obo) (Max) (F) 12p

@V(CB) (V) (Test Condition)

@Freq. (Hz) (Test Condition)